# NSN 5961-00-839-4685

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Inclosure Material:

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

400.0 breakdown voltage, collector-to-base, emitter open and 400.0 breakdown voltage, collector-to-emitter, base open and 5.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 1.00 amperes source cutoff current and 2.50 amperes source cutoff current

## Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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